

BTA420-800CT 3Q Hi-Com Triac

Rev.02 - 14 September 2021

**Product data sheet** 

## 1. General description

Planar passivated high commutation three quadrant triac in a TO220 plastic package intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. This "series CT" triac will commutate the full RMS current at the maximum rated junction temperature ( $T_{j(max)}$  = 150 °C) without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

#### 2. Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt
- High junction operating temperature capability
- High voltage capability
- Less sensitive gate for high noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only

### 3. Applications

- Applications subject to high temperature
- Heating controls
- High power motor control
- High power switching

#### 4. Quick reference data

able 1. Q	uick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Absolute	maximum rating					
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	-	800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 122 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	20	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	200	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	-	220	А
T <sub>j</sub>	junction temperature		-	-	150	°C
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2+ G+; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	35	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2+ G-; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	35	mA
		V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A; T2- G-; T <sub>I</sub> = 25 °C; <u>Fig. 7</u>	-	-	35	mA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 24 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
Dynamic	characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM} = 536 \text{ V}; \text{ T}_{\text{j}} = 150 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM}); exponential waveform; gate open circuit$	1250	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 20 \text{ A};$ $dV_{com}/dt = 10 \text{ V}/\mu s;$ gate open circuit	16	-	-	A/ms
		$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 20 \text{ A};$ $dV_{com}/dt = 1 \text{ V}/\mu s; \text{ gate open circuit}$	38	-	-	A/ms

#### **5. Pinning information**

Pin	Pinning infor Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	
2	T2	main terminal 2	205	
3	G	gate		sym051
mb	T2	mounting base; main terminal 2		
			1 2 3	

### 6. Ordering information

Table 3. Ordering information									
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date			
BTA420-800CT	TO220	BTA420-800CT,127	Tube	50	SOT78	13-Jun-2008			

### 7. Marking

#### Table 4. Marking codes

Type number	Marking codes	
	Assembly factory: d	Assembly factory: A
BTA420-800CT	BTA420 800CT PJdxxxx xx	BTA420 800CT PJAxxxx xx

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 122 °C; <u>Fig. 1;</u> <u>Fig. 2</u> ; <u>Fig. 3</u>	-	20	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 20 ms; Fig. 4; Fig. 5	-	200	A
		full sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 16.7 ms	-	220	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	-	200	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 70 mA	-	100	A/µs
I <sub>GM</sub>	peak gate current		-	2	А
$P_{GM}$	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

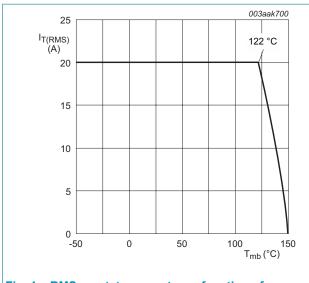
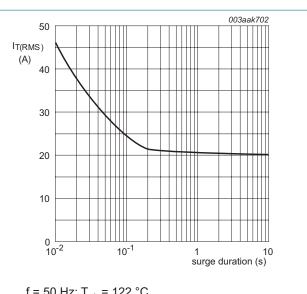
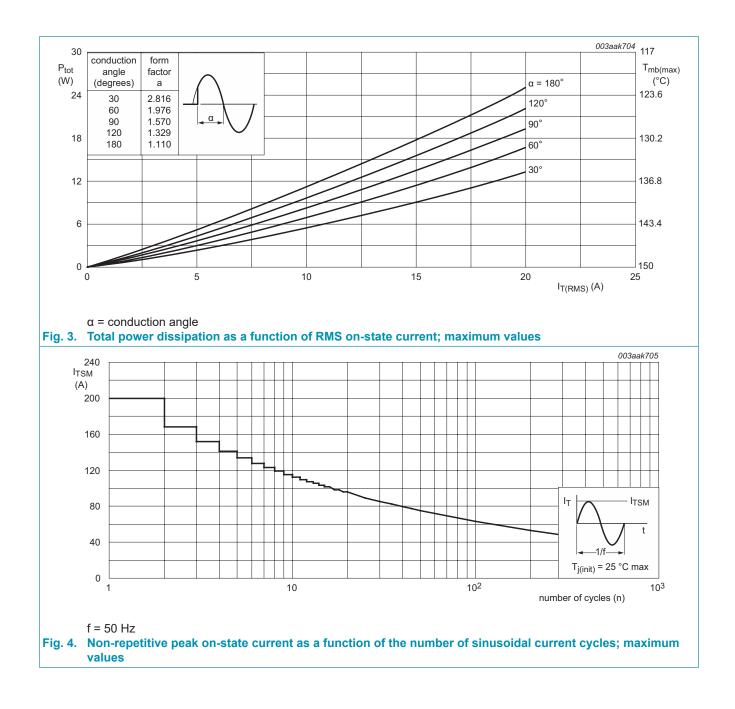


Fig. 1. RMS on-state current as a function of mounting base temperature; maximum values







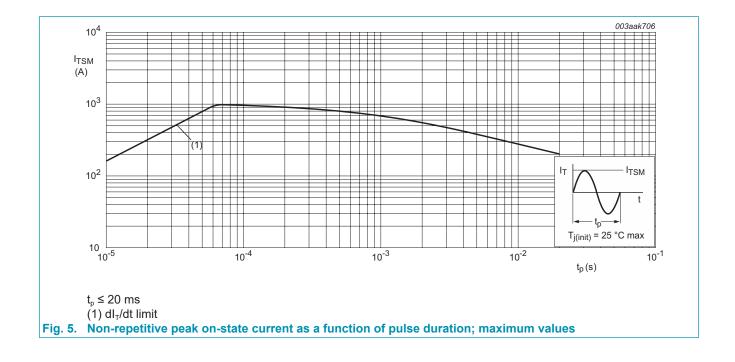
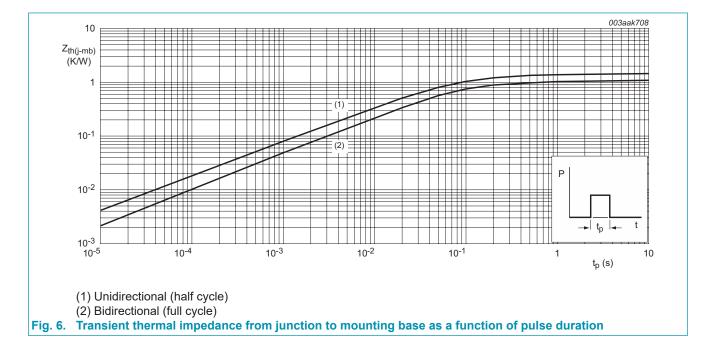


Table 6. Thermal characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
from ju	thermal resistance from junction to	full cycle; <u>Fig. 6</u>		-	-	1.1	K/W	
	mounting base	half cycle; <u>Fig. 6</u>		-	-	1.5	K/W	
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air		-	60	-	K/W	





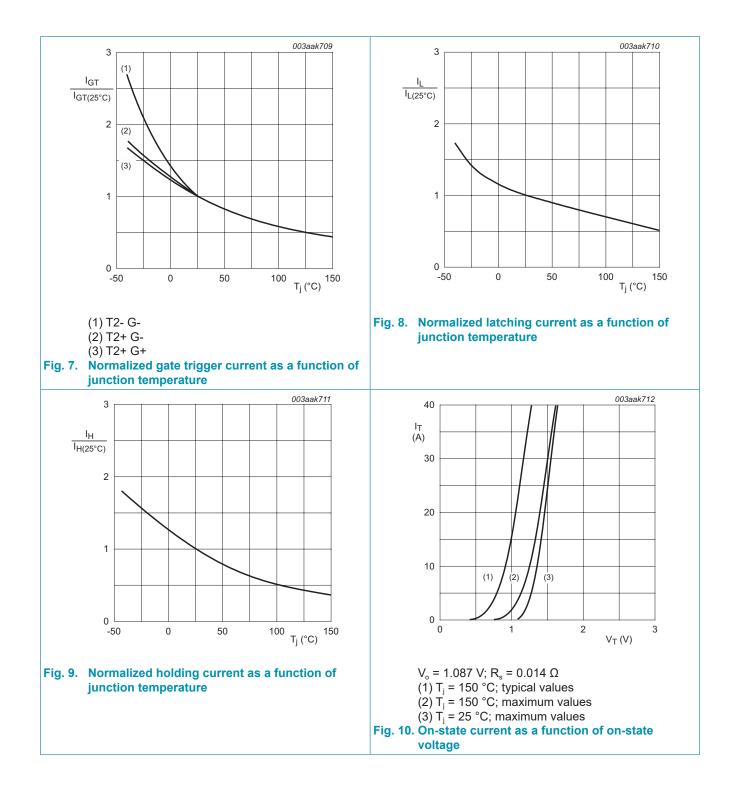
### **10. Characteristics**

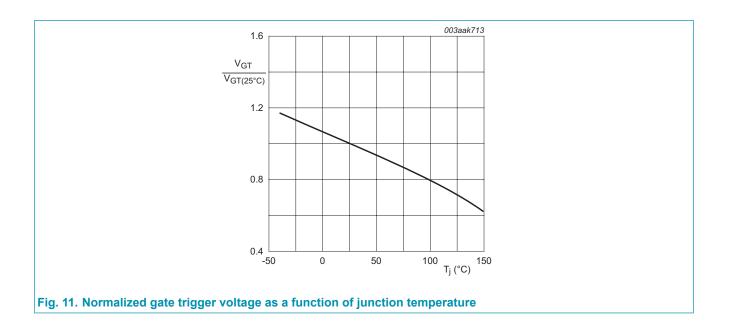
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I <sub>GT</sub>	gate trigger current	$V_D = 12 V; I_T = 0.1 A; T2+G+;$ T <sub>j</sub> = 25 °C; Fig. 7	-	-	35	mA
		$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2+ G-; T <sub>j</sub> = 25 °C; Fig. 7	-	-	35	mA
		$V_{\rm D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; Fig. 7	-	-	35	mA
I <sub>L</sub> I	latching current	$V_{\rm D}$ = 12 V; I <sub>G</sub> = 0.1 A; T2+ G+; T <sub>j</sub> = 25 °C; Fig. 8	-	-	50	mA
		$V_{\rm D}$ = 12 V; I <sub>G</sub> = 0.1 A; T2+ G-; T <sub>j</sub> = 25 °C; Fig. 8	-	-	60	mA
		V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; T2- G-; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	-	50	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	40	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 24 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
V <sub>GT</sub>	gate trigger voltage	$V_{\rm D}$ = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 11	-	0.7	1	V
		V <sub>D</sub> = 400 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 150 °C	0.2	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 800 V; T <sub>j</sub> = 150 °C	-	0.2	1	mA
Dynamic	characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	1250	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$\label{eq:V_D} \begin{array}{l} V_{\text{D}} = 400 \text{ V};  \text{T}_{\text{j}} = 150 ^{\circ}\text{C};  \text{I}_{\text{T(RMS)}} = 20 \text{ A}; \\ \text{d} \text{V}_{\text{com}} / \text{d} \text{t} = 10 \text{ V} / \mu \text{s}; \text{ gate open circuit} \end{array}$	16	-	-	A/ms
		$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 20 \text{ A};$ $dV_{com}/dt = 1 \text{ V}/\mu \text{s}; \text{ gate open circuit}$	38	-	-	A/ms

#### **WeEn Semiconductors**

**3Q Hi-Com Triac** 

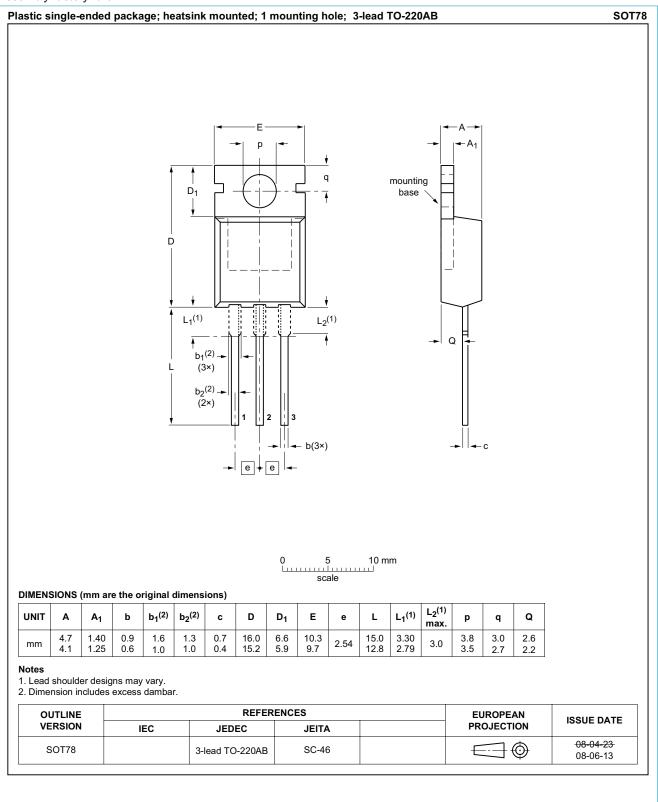
**BTA420-800CT** 





### **11. Package outline**

#### Assembly factory: d & A



#### BTA420-800CT 3Q Hi-Com Triac

## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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